

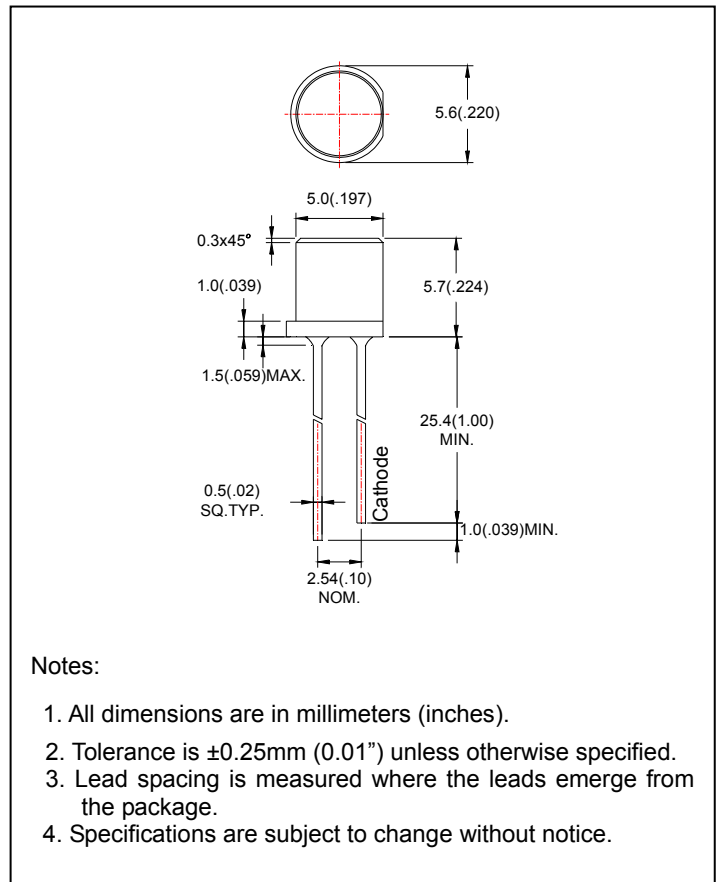
### ● Features:

1. Chip material: AlInGaN
2. Emitted color : Green
3. Lens Appearance : Green Trans
4. Cylindrical shape.
5. Low power consumption.
6. Compatible
7. Long life solid state reliability.
8. This product don't contained restriction substance, compliance ROHS standard.

### ● Applications:

1. TV set
2. Monitor
3. Telephone
4. Computer
5. Circuit board

### ● Package dimensions



### ● Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation	Pd	120	mW
Forward Current	I <sub>F</sub>	30	mA
Peak Forward Current* <sup>1</sup>	I <sub>FP</sub>	150	mA
Reverse Voltage	V <sub>R</sub>	5	V
Operating Temperature	Topr	-40°C~80°C	
Storage Temperature	Tstg	-40°C~85°C	
Soldering Temperature	Tsol	260°C (for 5 seconds)	

\*<sup>1</sup>Condition for I<sub>FP</sub> is pulse of 1/10 duty and 0.1msec width.

### ● Electrical and optical characteristics(Ta=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	$V_F$	$I_F=20mA$	-	3.5	4.0	V
Luminous Intensity	$I_v$	$I_F=20mA$	-	450	-	mcd
Reverse Current	$I_R$	$V_R=5V$	-	-	100	$\mu A$
Peak Wave Length	$\lambda_p$	$I_F=20mA$	-	525	-	nm
Dominant Wave Length	$\lambda_d$	$I_F=20mA$	520	-	530	nm
Spectral Line Half-width	$\Delta \lambda$	$I_F=20mA$	-	35	-	nm
Viewing Angle	$2\theta_{1/2}$	$I_F=20mA$	-	125	-	deg

### ● Typical electro-optical characteristics curves

Fig.1 Relative intensity vs. Wavelength

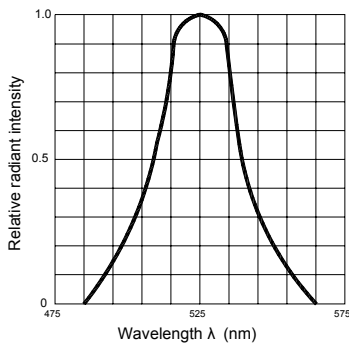


Fig.2 Forward current derating curve vs. Ambient temperature

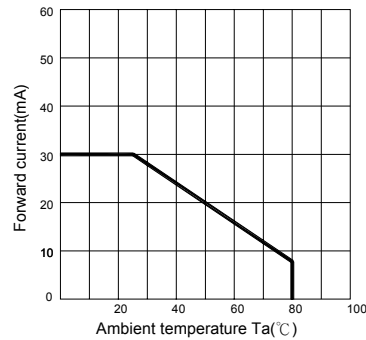


Fig.3 Forward current vs. Forward voltage

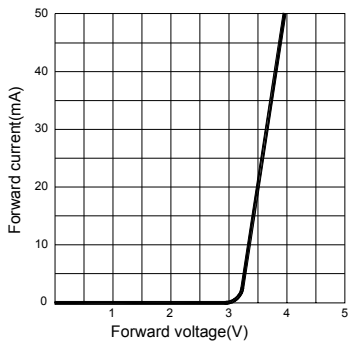


Fig.4 Relative luminous intensity vs. Ambient temperature

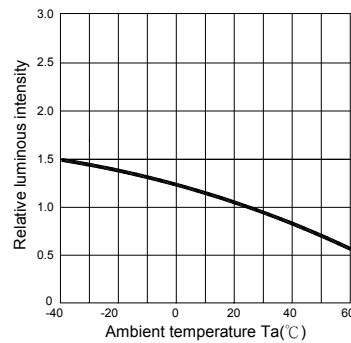


Fig.5 Relative luminous intensity vs. Forward current

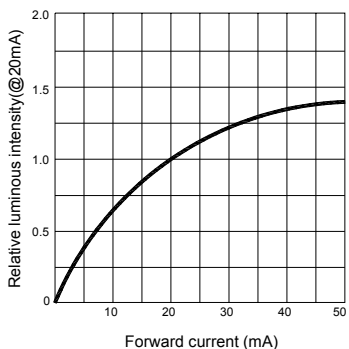
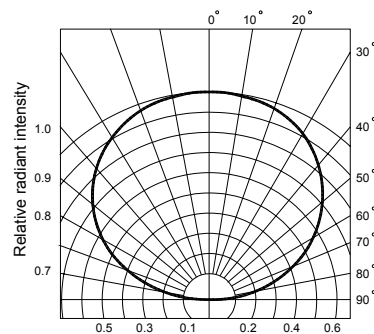


Fig.6 Radiation diagram



● **Bin Limits**

1. Intensity Bin Limits (At  $I_F=20\text{mA}$ )

Bin Code	Min. (mcd)	Max. (mcd)
:	:	:
R	120	240
S	180	360
T	280	550
U	410	820
V	620	1230
:	:	:

2. Color Bin Limits (At  $I_F=20\text{mA}$ ) : Dominant Wave Length  $\lambda_d(\text{nm})$

Bin Code	Min. (nm)	Max. (nm)
6	519	526
7	524	531

3.  $V_F$  Bin Limits (At  $I_F=20\text{mA}$ )

Bin Code	Min. (v)	Max. (v)
G	2.75	3.05
H	2.95	3.25
J	3.15	3.45
K	3.35	3.65
L	3.55	3.85
M	3.75	4.05

